

ND2406 SERIES

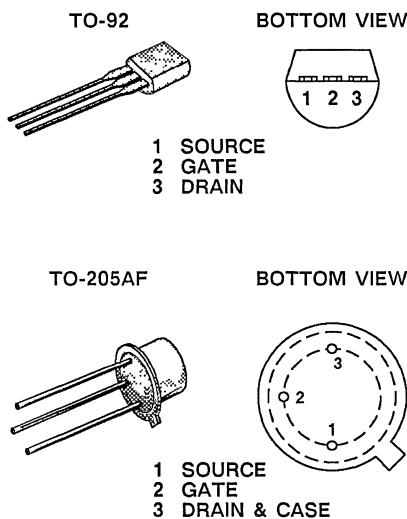
Siliconix
incorporated

N-Channel Depletion-Mode MOS Transistors

PRODUCT SUMMARY

PART NUMBER	V _{(BR)DSV} (V)	r _{DSON} (Ω)	I _D (A)	PACKAGE
ND2406L	240	6	0.23	TO-92
ND2406B	240	6	0.57	TO-205AF

Performance Curves: VDDV24 (See Section 7)



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

PARAMETERS/TEST CONDITIONS	SYMBOL	ND2406L	ND2406B ²	UNITS
Drain-Source Voltage	V _{DS}	240	240	V
Gate-Source Voltage	V _{GS}	±30	±20	
Continuous Drain Current T _A = 25°C	I _D	0.23	0.57	A
T _A = 100°C		0.14	0.36	
Pulsed Drain Current ¹	I _{DM}	0.90	1	
Power Dissipation T _A = 25°C	P _D	0.80	5	W
T _A = 100°C		0.32	2	
Operating Junction and Storage Temperature	T _j , T _{stg}	-55 to 150		°C
Lead Temperature (1/16" from case for 10 seconds)	T _L	300		

THERMAL RESISTANCE

THERMAL RESISTANCE	SYMBOL	ND2406L	ND2406B	UNITS
Junction-to-Ambient	R _{thJA}	156	125	°C/W

¹Pulse width limited by maximum junction temperature

²Reference case for all temperature testing

ELECTRICAL CHARACTERISTICS ¹			LIMITS					
PARAMETER	SYMBOL	TEST CONDITIONS	TYP ²	ND2406L		ND2406B		UNIT
				MIN	MAX	MIN	MAX	
STATIC								
Drain-Source Breakdown Voltage	V _{(BR)DSV}	V _{GS} = -9 V, I _D = 10 μA	260	240		240		V
Gate-Source Cutoff Voltage	V _{GS(OFF)}	V _{DS} = 5 V, I _D = 10 μA	-2.8	-1.5	-4.5	-1.5	-4.5	
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V V _{GS} = ±20 V	±1		±10		±10	nA
Drain Cutoff Current	I _{D(OFF)}	V _{DS} = 180 V V _{GS} = -9 V	0.04		1		1	μA
Drain Saturation Current ³	I _{DSS}	V _{DS} = 10 V, V _{GS} = 0 V	640	40		40		mA
Drain-Source On-Resistance ³	r _{DS(ON)}	V _{GS} = 2 V, I _D = 30 mA	3					Ω
		V _{GS} = 0 V I _D = 30 mA	3.5		6		6	
Forward Transconductance ³	g _{FS}	V _{DS} = 10 V, I _D = 30 mA	110					ms
Common Source Output Conductance ³	g _{os}		70					μs
DYNAMIC								
Input Capacitance	C _{iss}	V _{DS} = 25 V V _{GS} = -5 V f = 1 MHz	70		120		120	pF
Output Capacitance	C _{oss}		20		30		30	
Reverse Transfer Capacitance	C _{rss}		10		15		15	
SWITCHING								
Turn-On Time	t _{d(ON)}	V _{DD} = 25 V, R _L = 830 Ω I _D = 30 mA, V _{GEN} = -5 V R _G = 25 Ω (Switching time is essentially independent of operating temperature)	15					ns
	t _r		75					
Turn-Off Time	t _{d(OFF)}		40					
	t _f		100					

NOTES: 1. T_A = 25 °C unless otherwise noted, T_C = 25 °C for ND2406B.

2. For design aid only, not subject to production testing.

3. Pulse test; PW = 300 μs, duty cycle ≤ 2%.

